Preferred Device

Small Signal MOSFET 200 mAmps, 60 Volts

N-Channel TO-92

Features

Pb–Free Packages are Available*



Rating	Symbol	Value	Unit
Drain Source Voltage	V _{DSS}	60	Vdc
Drain–Gate Voltage ($R_{GS} = 1.0 \text{ M}\Omega$)	V_{DGR}	60	Vdc
Gate–Source Voltage – Continuous – Non–repetitive ($t_p \le 50 \mu s$)	V _{GS} V _{GSM}	±20 ±40	Vdc Vpk
Drain Current - Continuous - Pulsed	I _D	200 500	mAdc
Total Power Dissipation @ T _C = 25°C Derate above 25°C	P _D	350 2.8	mW mW/°C
Operating and Storage Temperature Range	T _J , T _{stg}	-55 to +150	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	357	°C/W
Maximum Lead Temperature for Soldering Purposes, 1/16" from case for 10 seconds	DZSC	300	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



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200 mAMPS 60 VOLTS

 $R_{DS(on)} = 5 \Omega$

N-Channel D D

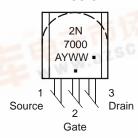


1 2 3

BULK PACK

BENT LEAD TAPE & REEL AMMO PACK

MARKING DIAGRAM AND PIN ASSIGNMENT



A = Assembly Location

Y = Year WW = Work Week

■ = Pb-Free Package (Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted)

	Symbol	Min	Max	Unit	
OFF CHARACTERISTICS					
Drain-Source Breakdown Voltag	e $(V_{GS} = 0, I_D = 10 \mu Adc)$	V _{(BR)DSS}	60	-	Vdc
Zero Gate Voltage Drain Current	(V _{DS} = 48 Vdc, V _{GS} = 0) (V _{DS} = 48 Vdc, V _{GS} = 0, T _J = 125°C)	I _{DSS}	- -	1.0 1.0	μAdc mAdc
Gate-Body Leakage Current, Fo	rward $(V_{GSF} = 15 \text{ Vdc}, V_{DS} = 0)$	I _{GSSF}	-	-10	nAdc
ON CHARACTERISTICS (Note	1)				
Gate Threshold Voltage	$(V_{DS} = V_{GS}, I_D = 1.0 \text{ mAdc})$	V _{GS(th)}	0.8	3.0	Vdc
Static Drain-Source On-Resista	nce $(V_{GS} = 10 \text{ Vdc}, I_D = 0.5 \text{ Adc})$ $(V_{GS} = 4.5 \text{ Vdc}, I_D = 75 \text{ mAdc})$	r _{DS(on)}	- -	5.0 6.0	Ω
Drain-Source On-Voltage	$(V_{GS} = 10 \text{ Vdc}, I_D = 0.5 \text{ Adc})$ $(V_{GS} = 4.5 \text{ Vdc}, I_D = 75 \text{ mAdc})$	V _{DS(on)}	- -	2.5 0.45	Vdc
On-State Drain Current	(V _{GS} = 4.5 Vdc, V _{DS} = 10 Vdc)	I _{d(on)}	75	-	mAdc
Forward Transconductance	$(V_{DS} = 10 \text{ Vdc}, I_D = 200 \text{ mAdc})$	9fs	100	-	μmhos
DYNAMIC CHARACTERISTICS					
Input Capacitance		C _{iss}	-	60	pF
Output Capacitance	$(V_{DS} = 25 \text{ V}, V_{GS} = 0,$ f = 1.0 MHz)	C _{oss}	-	25	
Reverse Transfer Capacitance	,	C _{rss}	_	5.0	
SWITCHING CHARACTERISTIC	CS (Note 1)				
Turn-On Delay Time	(V _{DD} = 15 V, I _D = 500 mA,	t _{on}	_	10	ns
Turn-Off Delay Time	$R_G = 25 \Omega$, $R_L = 30 \Omega$, $V_{gen} = 10 V$)	t _{off}	_	10	

^{1.} Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%.

ORDERING INFORMATION

Device	Package	Shipping [†]
2N7000	TO-92	1000 Units / Bulk
2N7000G	TO-92 (Pb-Free)	1000 Units / Bulk
2N7000RLRA	TO-92	2000 Tape & Reel
2N7000RLRAG	TO-92 (Pb-Free)	2000 Tape & Reel
2N7000RLRM	TO-92	2000 Tape & Ammo Box
2N7000RLRMG	TO-92 (Pb-Free)	2000 Tape & Ammo Box
2N7000RLRP	TO-92	2000 Tape & Ammo Box
2N7000RLRPG	TO-92 (Pb-Free)	2000 Tape & Ammo Box

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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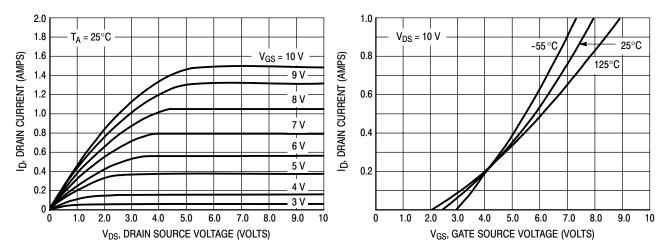


Figure 1. Ohmic Region

Figure 2. Transfer Characteristics

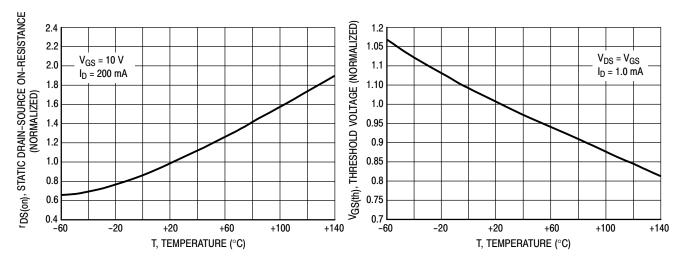
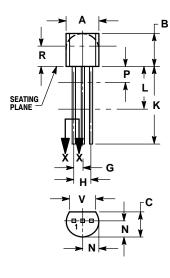


Figure 3. Temperature versus Static Drain-Source On-Resistance

Figure 4. Temperature versus Gate Threshold Voltage

PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-11 **ISSUE AM**

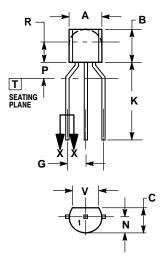


STRAIGHT LEAD **BULK PACK**



- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
 CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
 LEAD DIMENSION IS UNCONTROLLED IN P AND
- BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
P		0.100		2.54
R	0.115		2.93	
V	0.135		3.43	



BENT LEAD TAPE & REEL AMMO PACK



NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.
 CONTOUR OF PACKAGE BEYOND
 DIMENSION R IS UNCONTROLLED.

- LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	MILLIMETERS		
DIM	MIN	MAX	
Α	4.45	5.20	
В	4.32	5.33	
С	3.18	4.19	
D	0.40	0.54	
G	2.40	2.80	
J	0.39	0.50	
K	12.70		
N	2.04	2.66	
Р	1.50	4.00	
R	2.93		
٧	3.43		

STYLF 22

SOURCE PIN 1.

> 3. DRAIN

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